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Single general-purpose switching diodes Rev. 03 — 16 August 2007

Product data sheet

Product profile 1.

1.1 General description

Single general-purpose switching diodes, fabricated in planar technology, and encapsulated in small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) packages.

	Table 1	.	Product	overview
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Type number	Package	Package	
	NXP	JEITA	
BAV102	SOD80C	-	single
BAV103			

package

Voltage clamping

Reverse polarity protection

1.2 Features

High switching speed: $t_{rr} \le 50$ ns Low capacitance: $C_d \le 5 \text{ pF}$ Low leakage current Small hermetically sealed glass SMD

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		<u>[1][2]</u> _	-	250	mA
V _R	reverse voltage					
	BAV102		-	-	150	V
	BAV103		-	-	200	V
t _{rr}	reverse recovery time		<u>[3]</u>	-	50	ns

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.



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2. Pinning information

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode	k	1 - 2 006aab040

[1] The marking band indicates the cathode.

3. Ordering information

Table 4. Ordering information							
Type number Package							
	Name	Description	Version				
BAV102	-	hermetically sealed glass surface-mounted package;	SOD80C				
BAV103		2 connectors					

4. Marking

Table 5. Marking codes		
Type number	Marking code ^[1]	
BAV102	marking band	
BAV103		
[1] green: made in Philippines		

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage				
	BAV102		-	200	V
	BAV103		-	250	V
V _R	reverse voltage				
	BAV102		-	150	V
	BAV103		-	200	V
l _F	forward current		<u>[1][2]</u> _	250	mA
I _{FRM}	repetitive peak forward current		-	625	mA

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Table 6.	Limiting	values	CO	ntinu	led

In accordance with the Absolute Maximum Rating System (IEC 60134).

		· · · · · · · · · · · · · · · · · · ·	/		
Symbol	Parameter	Conditions	Min	Max	Unit
I _{FSM}	non-repetitive peak	square wave	[3]		
	forward current	$t_p = 1 \ \mu s$	-	9	А
		t _p = 100 μs	-	3	А
		t _p = 1 s	-	1	А
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[2] _	400	mW
Tj	junction temperature		-	175	°C
T _{amb}	ambient temperature		-65	+175	°C
T _{stg}	storage temperature		-65	+175	°C

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] $T_j = 25 \ ^{\circ}C$ prior to surge.

6. Thermal characteristics

Table 7.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	375	K/W	
R _{th(j-t)}	thermal resistance from junction to tie-point		-	-	300	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

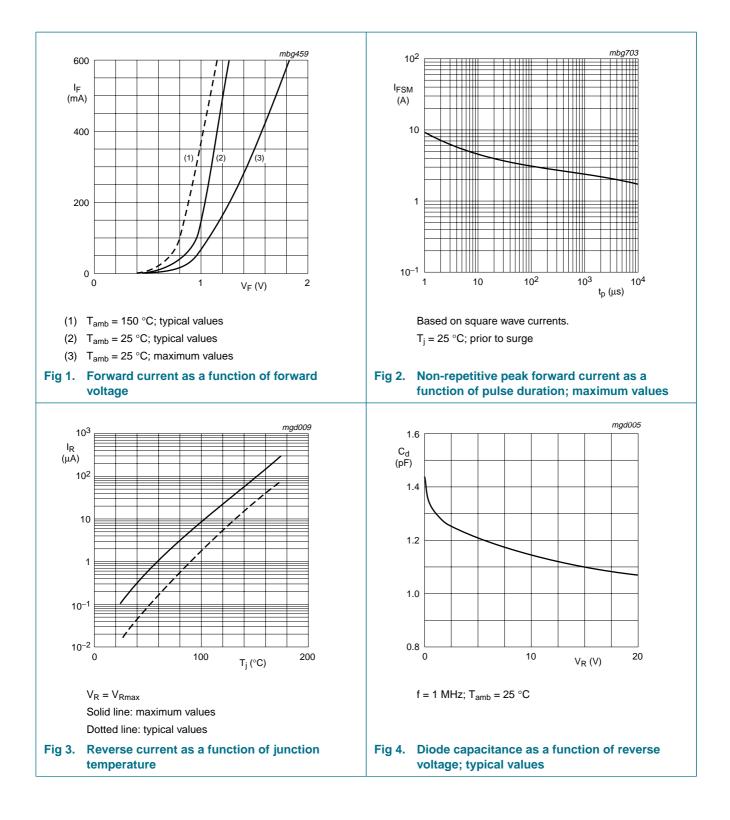
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage		<u>[1]</u>			
		I _F = 100 mA	-	-	1.0	V
		I _F = 200 mA	-	-	1.25	V
I _R	reverse current					
	BAV102	V _R = 150 V	-	-	100	nA
		V _R = 150 V; T _j = 150 °C	-	-	100	μΑ
	BAV103	V _R = 200 V	-	-	100	nA
		V_R = 200 V; T_j = 150 °C	-	-	100	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	-	-	5	pF
t _{rr}	reverse recovery time		[2] _	-	50	ns

[2] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 $\Omega;$ measured at I_R = 3 mA.

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BAV102; BAV103

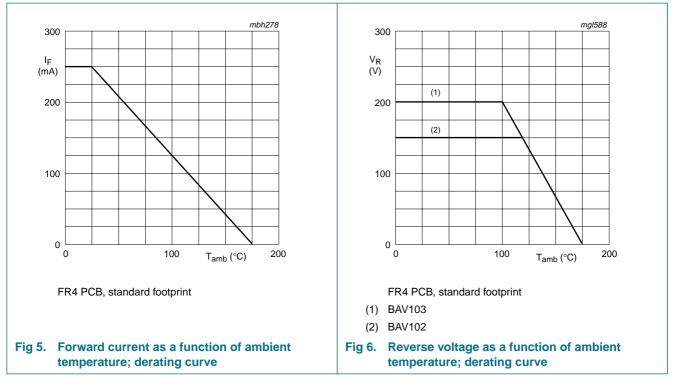
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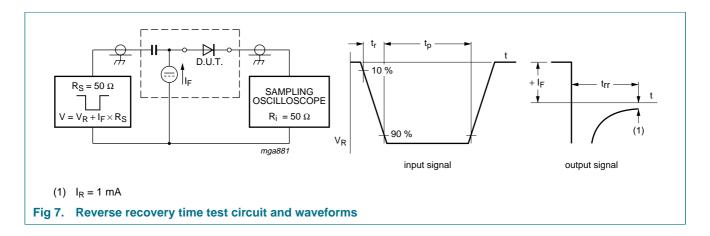
NXP Semiconductors

BAV102; BAV103

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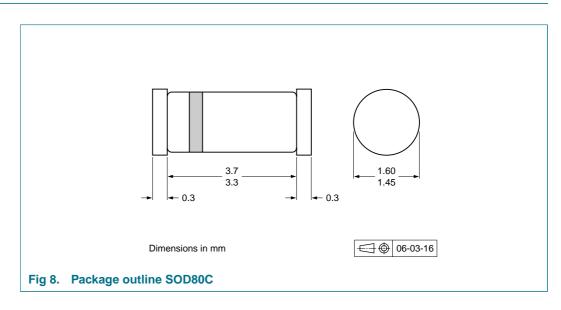


8. Test information



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9. Package outline



10. Packing information

Table 9. Packing methods

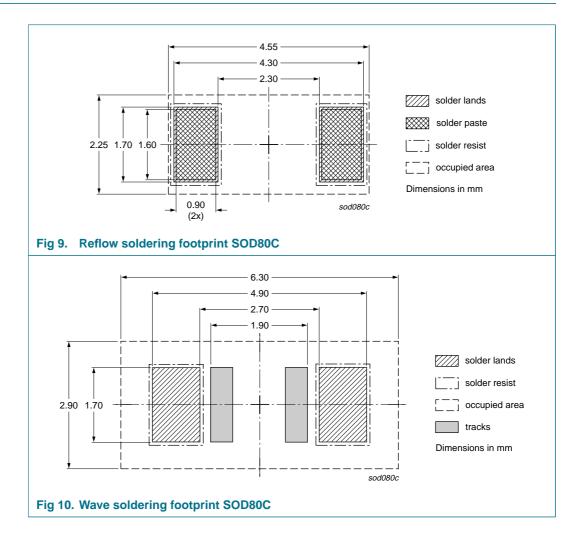
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			2500	10000
BAV102	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135
BAV103				

[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAV102_BAV103_3	20070816	Product data sheet	-	BAV100_2	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 				
	 Legal texts have been adapted to the new company name where appropriate. 				
	 Type numbers BAV100 and BAV101 have been removed 				
	 <u>Section 1.1 "General description"</u>: amended 				
	<u>Table 1 "Product overview"</u> : added				
	 <u>Table 2 "Quick reference data"</u>: added 				
	 <u>Section 3 "Ordering information"</u>: added 				
	<u>Figure 7</u> : figure title amended				
	 Figure 8: superseded by minimized package outline drawing 				
	 <u>Section 10 "Packing information"</u>: added 				
	 <u>Section 11 "Soldering"</u>: added 				
	 <u>Section 13 "Legal information"</u>: updated 				
BAV100_2	19960917	Product specification	-	BAV100_1	
BAV100 1	19960423	Product specification	-	-	

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Date of release: 16 August 2007 Document identifier: BAV102_BAV103_3

